FAIRCHILD

SEMICONDUCTOR

SGR15N40L / SGU15N40L

General Description

Insulated Gate Bipolar Transistors (IGBTs) with a trench gate structure provide superior conduction and switching performance in comparison with transistors having a planar gate structure. They also have wide noise immunity. These devices are very suitable for strobe applications

Features

- High input impedance
- High peak current capability (130A)
- · Easy gate drive

Application

Strobe flash.



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description	SGR / SGU15N40L	Units	
V _{CES}	Collector - Emitter Voltage	400	V	
V _{GES}	Gate - Emitter Voltage	± 6	V	
I _{CM (1)}	Pulsed Collector Current	130	A	
P _C	Maximum Power Dissipation @ T _C	= 25°C 45	W	
TJ	Operating Junction Temperature	-40 to +150	°C	
T _{stg}	Storage Temperature Range	-40 to +150	°C	
TL	Maximum Lead Temp. for soldering purposes, 1/8" from case for 5 seconds	300	°C	

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		3.0	°C/W
R _{0JA} (D-PAK)	Thermal Resistance, Junction-to-Ambient (PCB Mount) (2)		50	°C/W
R _{θJA} (I-PAK)	Thermal Resistance, Junction-to-Ambient		110	°C/W

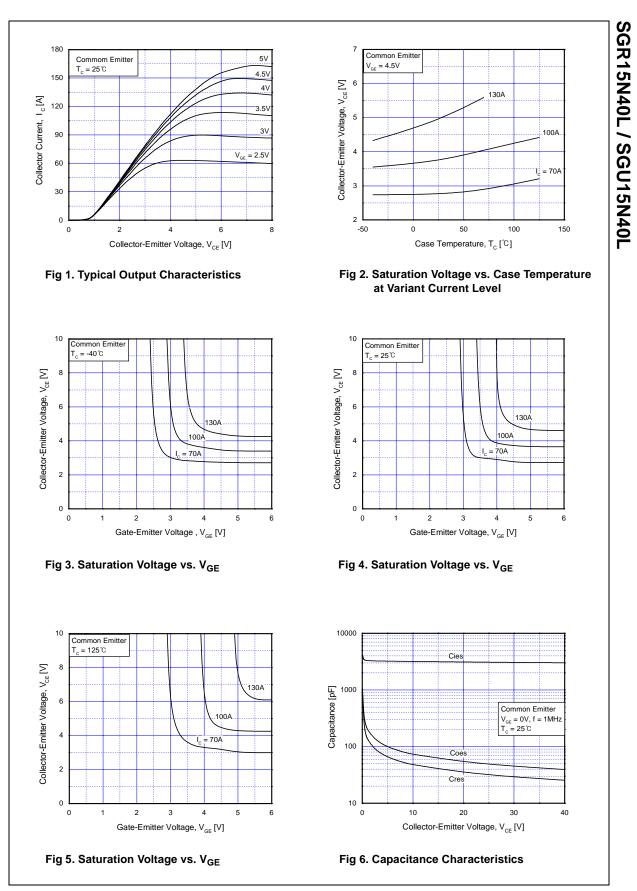
Notes :

(2) Mounted on 1" square PCB (FR4 or G-10 Material)

IGBT

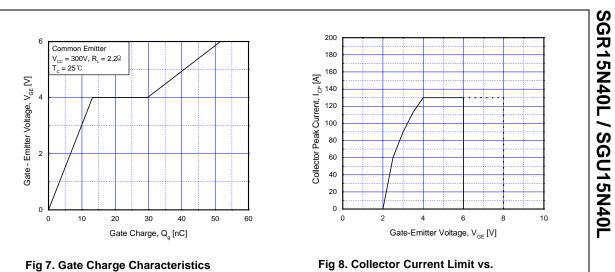
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics					
V _{CES}	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 1mA$	450			V
ES	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			10	uA
ES	G - E Leakage Voltage	$V_{GE} = V_{GES}, V_{CE} = 0V$			±0.1	uA
n Cha	racteristics					
GE(th)	G - E Threshold Voltage	$I_{C} = 1 \text{mA}, V_{CE} = V_{GE}$	0.5	1.0	1.4	V
CE(sat)	C - E Saturation Current	I _C = 130A, V _{GE} = 4.5V	2.0	4.5	8.0	V
oes	Output Capacitance	V _{GE} = 0V, V _{CE} = 30V, f = 1MHz		45		pF
ynami ^{ies}	c Characteristics	1		3000	1	pF
res	Reverse Transfer Capacitance	f = 1MHz		30		pF
	· · · ·					
witchi	ng Characteristics				1	
(on)	Turn-On Delay Time	V _{CC} = 300V, I _C = 130A,		0.08		us
	Rise Time	$V_{GE} = 4.5V, R_G = 15\Omega$		1.4		us
(off)	Turn-Off Delay Time	Resistive Load		0.1	0.5	us
	Fall Time			1.1	2.0	us

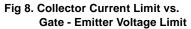
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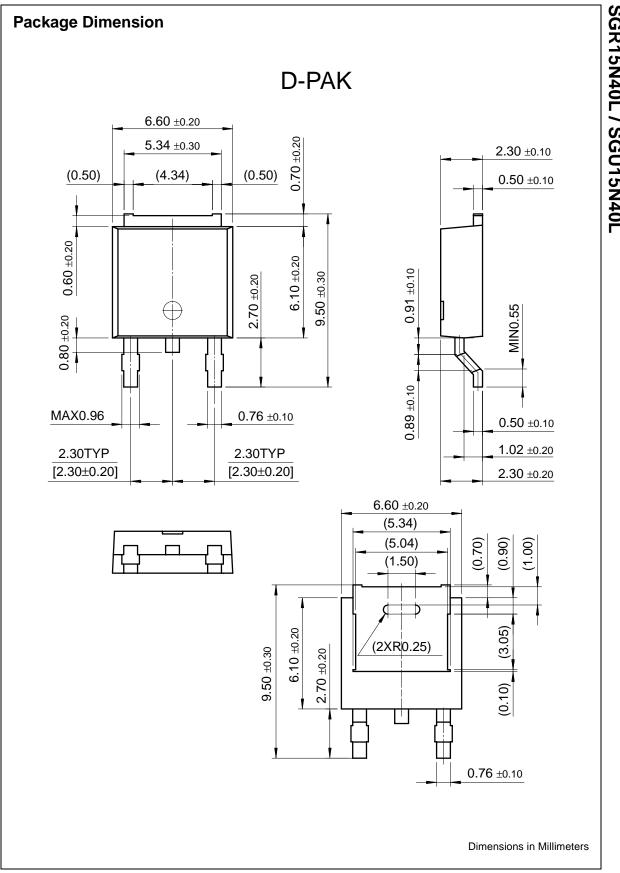


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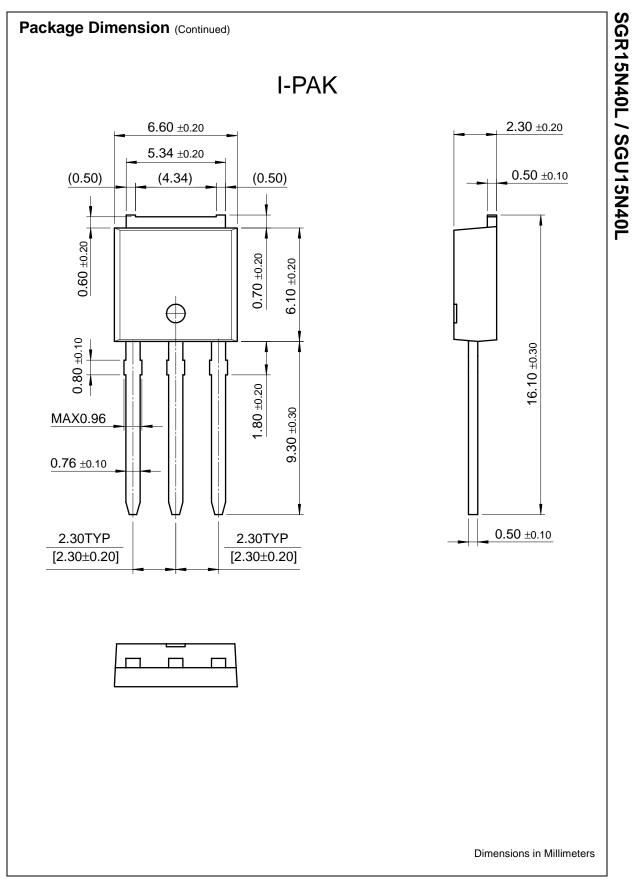






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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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company	 High input impedance High peak current capability (130A) Easy gate drive 		

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Applications

• Strobe flash

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Product status/pricing/packaging

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SGU15N40LTU	Full Production	\$1.88	Purchase	TO-251(IPAK)	3	RAIL
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Application notes						
AN-9006: AN-900)6 IGBT Applicat	ion Note for	Camera Strob	e (146 K)		
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